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DATA SHEET

For a complete data sheet, please also download:

- The IC06 74HC/HCT/HCU/HCMOS Logic Family Specifications
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Information
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Outlines

74HC/HCT541
Octal buffer/line driver; 3-state

Product specification
File under Integrated Circuits, IC06

December 1990

Philips
Semiconductors

PHILIPS

Octal buffer/line driver; 3-state 74HC/HCT541

FEATURES

- Non-inverting outputs
- Output capability: bus driver
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT541 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT541 are octal non-inverting buffer/line drivers with 3-state outputs. The 3-state outputs are controlled by the output enable inputs $\overline{OE}_1$ and $\overline{OE}_2$. A HIGH on $\overline{OE}_n$ causes the outputs to assume a high impedance OFF-state.
The "541" is identical to the "540" but has non-inverting outputs.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PHL}/ t_{PLH}	propagation delay A_n to Y_n	C_L = 15 pF; V_{CC} = 5 V	10	12	ns
C_I	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per buffer	notes 1 and 2	37	39	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in µW):

   $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

   f_i = input frequency in MHz

   f_o = output frequency in MHz

   $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

   C_L = output load capacitance in pF

   V_{CC} = supply voltage in V

2. For HC the condition is V_I = GND to V_{CC}
   For HCT the condition is V_I = GND to V_{CC} − 1.5 V

ORDERING INFORMATION

See *"74HC/HCT/HCU/HCMOS Logic Package Information"*.

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 19	$\overline{OE}_1$, $\overline{OE}_2$	output enable input (active LOW)
2, 3, 4, 5, 6, 7, 8, 9	A_0 to A_7	data inputs
10	GND	ground (0 V)
18, 17, 16, 15, 14, 13, 12, 11	Y_0 to Y_7	bus outputs
20	V_{CC}	positive supply voltage

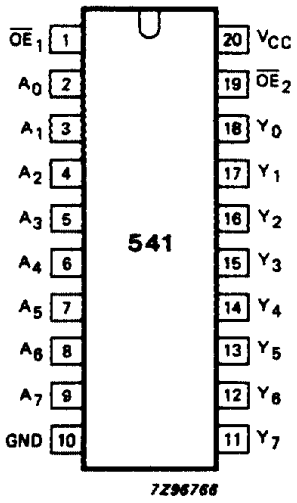


Fig.1 Pin configuration.

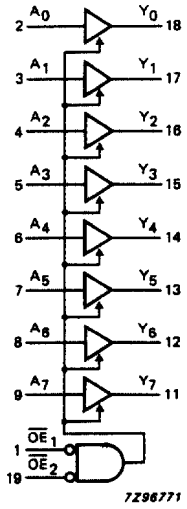


Fig.2 Logic symbol.

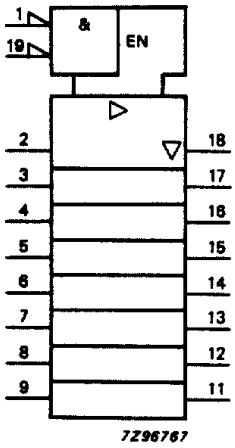


Fig.3 IEC logic symbol.

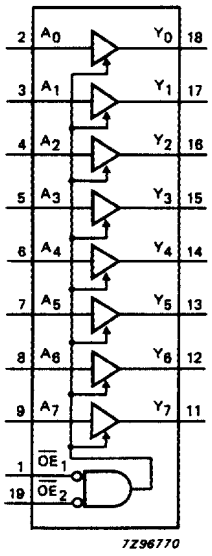


Fig.4 Functional diagram.

FUNCTION TABLE

INPUTS			OUTPUT
$\overline{OE}_1$	$\overline{OE}_2$	A_n	Y_n
L	L	L	L
L	L	H	H
X	H	X	Z
H	X	X	Z

Notes

1. H = HIGH voltage level
   L = LOW voltage level
   X = don't care
   Z = high impedance OFF-state

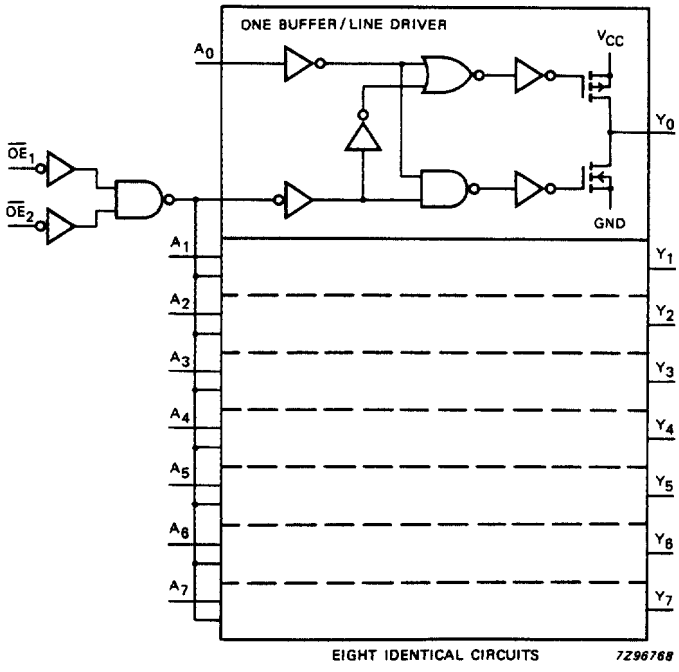


Fig.5 Logic diagram.

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see *"74HC/HCT/HCU/HCMOS Logic Family Specifications"*.

Output capability: bus driver
I_{CC} category: MSI

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HC								V_{CC} (V)	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}/ t_{PLH}	propagation delay A_n to Y_n		33 12 10	115 23 20		145 29 25		175 35 30	ns	2.0 4.5 6.0	Fig.6
t_{PZH}/ t_{PZL}	3-state output enable time $\overline{OE}$ to Y_n		55 20 16	160 32 27		200 40 34		240 48 41	ns	2.0 4.5 6.0	Fig.7
t_{PHZ}/ t_{PLZ}	3-state output disable time $\overline{OE}$ to Y_n		61 22 18	160 32 27		200 40 34		240 48 41	ns	2.0 4.5 6.0	Fig.7
t_{THL}/ t_{TLH}	output transition time		14 5 4	60 12 10		75 15 13		90 18 15	ns	2.0 4.5 6.0	Fig.6

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see *"74HC/HCT/HCU/HCMOS Logic Family Specifications"*.

Output capability: bus driver
I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

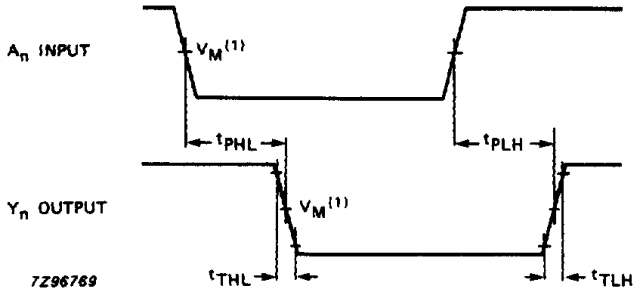
INPUT	UNIT LOAD COEFFICIENT
$\overline{OE}_1$	1.50
$\overline{OE}_2$	1.00
A_n	0.70

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

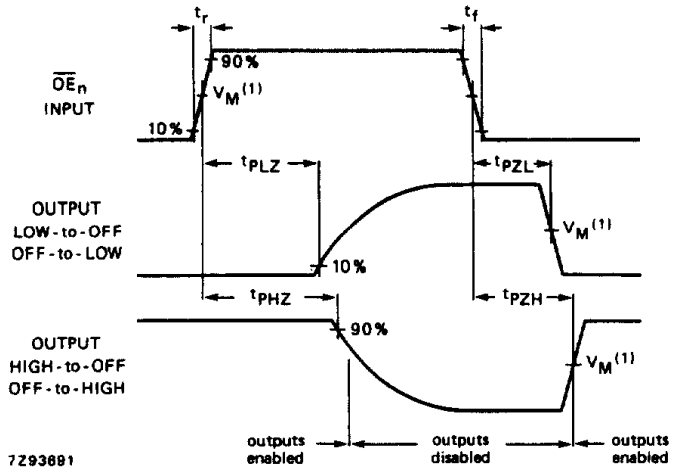
SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HCT								V_{CC} (V)	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}/ t_{PLH}	propagation delay A_n to Y_n		15	28		35		42	ns	4.5	Fig.6
t_{PZH}/ t_{PZL}	3-state output enable time $\overline{OE}$ to Y_n		21	35		44		53	ns	4.5	Fig.7
t_{PHZ}/ t_{PLZ}	3-state output disable time $\overline{OE}$ to Y_n		21	35		44		53	ns	4.5	Fig.7
t_{THL}/ t_{TLH}	output transition time		5	12		15		18	ns	4.5	Fig.6

AC WAVEFORMS



(1) HC : V_M = 50%; V_I = GND to V_{CC}.
HCT: V_M = 1.3 V; V_I = GND to 3 V.

Fig.6 Waveforms showing the input (A_n) to output (Y_n) propagation delays and the output transition times.



(1) HC : V_M = 50%; V_I = GND to V_{CC}.
HCT: V_M = 1.3 V; V_I = GND to 3 V.

Fig.7 Waveforms showing the 3-state enable and disable times.

PACKAGE OUTLINES

See *"74HC/HCT/HCU/HCMOS Logic Package Outlines"*.